

## AUDIO AMPLIFIER

The TBA915 is a monolithic integrated a. f. amplifier designed for use in small communication receivers, where low battery drain is of paramount importance. The output power of the device is 500 mW and the zero-signal current is only 2 mA (typ.). The circuit can be squelched to a stand-by current of 0,4 mA.

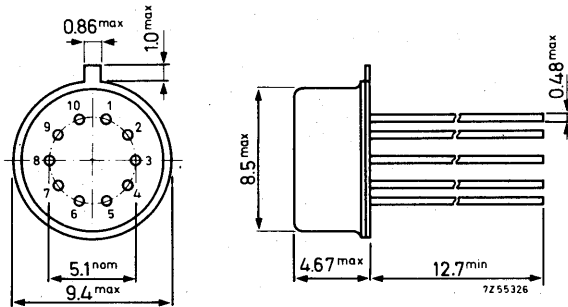
### QUICK REFERENCE DATA

Supply voltage	$V_P$	nom.	12	V
Output power at $R_L = 20 \Omega$	$P_O$	typ.	500	mW
Input signal for $P_O = 500 \text{ mW}$	$V_i$	typ.	10	mV
Input impedance	$R_i$	typ.	9	k $\Omega$
Total current (no signal) (squelched)	$I_{tot}$	typ.	2	mA
	$I_{tot}$	typ.	0,4	mA

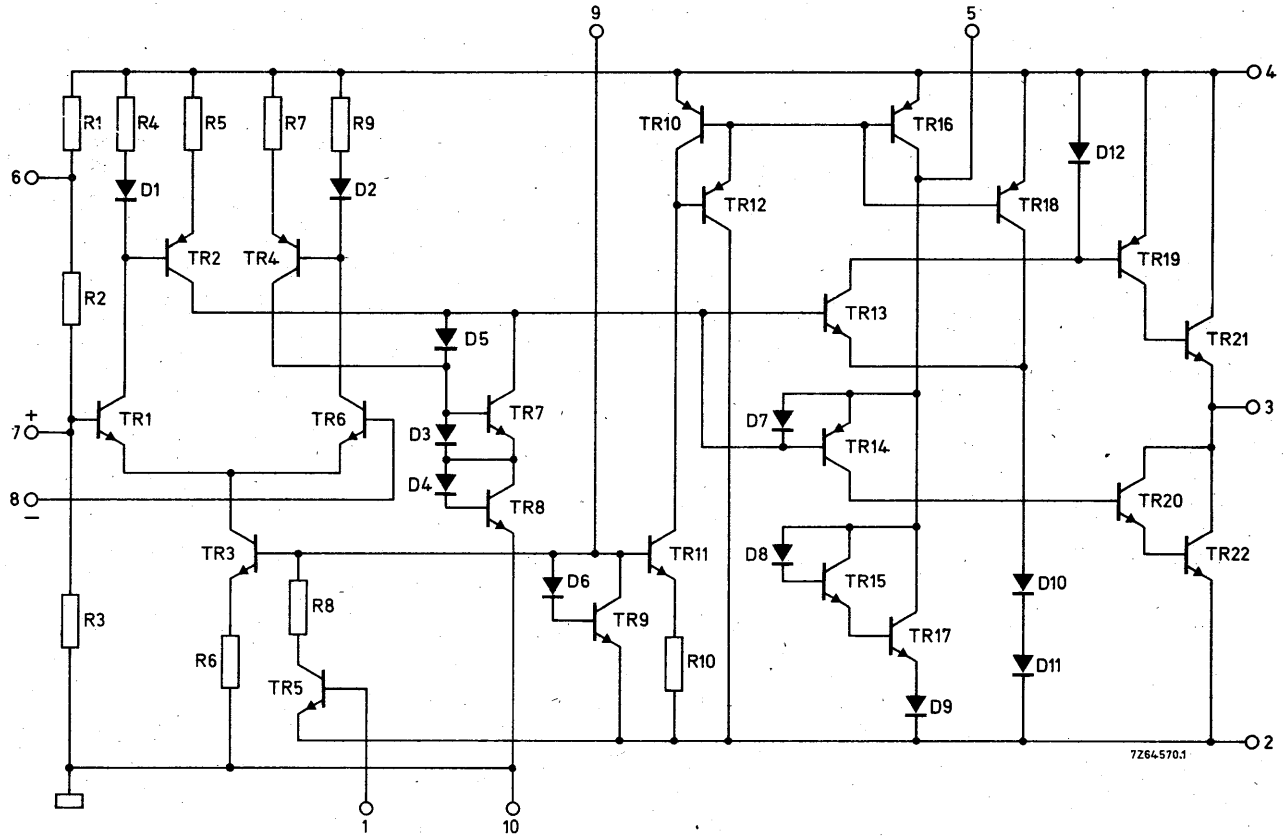
### PACKAGE OUTLINE

Dimensions in mm

TO-74 (reduced height)



CIRCUIT DIAGRAM



7284570.1

**RATINGS** Limiting values in accordance with the Absolute Maximum System (IEC 134).

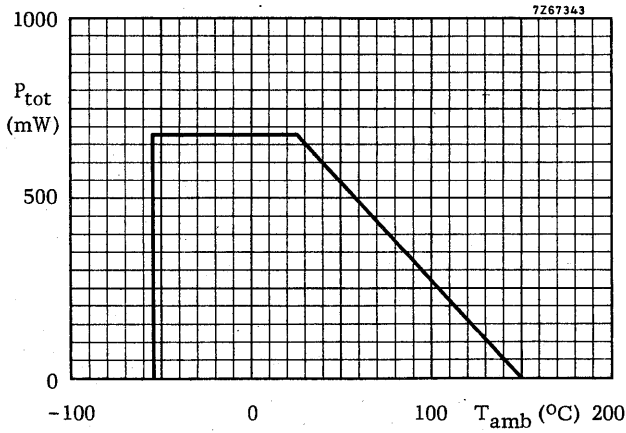
Voltages (pin 2 must be externally connected to pin 10)

Pin No. 4 voltage	$V_{4-2}$	max.	17	V
Pin No. 8 voltage	$\pm V_{8-7}$	max.	5	V
Pin No. 3 voltage	$V_{3-2}$	max.	17	V

Currents

Pin No. 4 current	$I_4$	max.	350	mA
Pin No. 3 current	$\pm I_3$	max.	350	mA
Pin No. 7 current	$I_7$	max.	0,5	mA
Pin No. 8 current	$I_8$	max.	0,5	mA
Pin No. 5 current	$I_5$	max.	5	mA
Pin No. 9 current	$I_9$	max.	5	mA
Pin No. 1 current	$\left\{ \begin{array}{l} +I_1 \\ -I_1 \end{array} \right.$	max.	1	mA
		max.	10	$\mu A$

Total power dissipation



Temperatures

Storage temperature	$T_{stg}$	-55 to +125	°C
Operating ambient temperature see derating curve above	$T_{amb}$	-55 to +125	°C

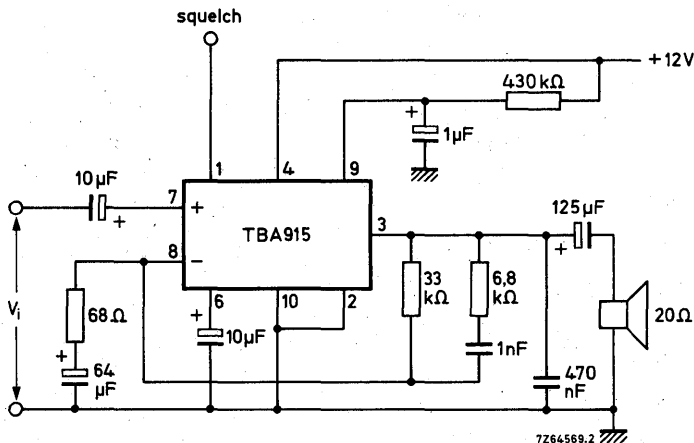
# TBA915

## CHARACTERISTICS at $T_{amb} = 25\text{ }^{\circ}\text{C}$ ; $V_P = 12\text{ V}$

Measured in the test circuit below

<u>Output power</u> at $d_{tot} = 5\%$	$P_O$	typ.	500	mW
<u>Bandwidth</u> (-3 dB)	B	>	6	kHz
<u>Total current</u> (d.c.)				
→ no signal	$I_{tot}$	typ.	2	mA
		<	3,7	mA
no signal with squelch	$I_{tot}$	typ.	0,4	mA
with signal at $P_O = 500\text{ mW}$	$I_{tot}$	typ.	72	mA
<u>Total distortion</u> at $P_O = 500\text{ mW}$	$d_{tot}$	typ.	2,5	%
		<	5	%
<u>Input signal</u> at $P_O = 500\text{ mW}$	$V_i$	typ.	10	mV
		<	15	mV
<u>Input impedance</u>	$ Z_i $	typ.	9	k $\Omega$
<u>Signal-to-noise ratio</u>				
related to $P_O = 500\text{ mW}$				
$R_S = 600\text{ }\Omega$ ; B = 300 Hz to 6 kHz	$\frac{S}{N}$	typ.	72	dB
<u>Bias current</u>	$I_Q$	>	25	$\mu\text{A}$

Test circuit



## → SQUELCH REQUIREMENTS at $I_Q = 25\text{ }\mu\text{A}$

Squelch "on"	$\left\{ \begin{array}{l} V_1 \\ I_1 \end{array} \right.$	>	800	mV
		>	10	$\mu\text{A}$
Squelch "off"	$V_1$	<	400	mV